

Features

- Low RDS(on)
- Operated at Low Logic Level Gate Drive
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 833°C/W Junction to Ambient (Note 2)
- Thermal Resistance: 260°C/W Junction to Lead (Note 2)

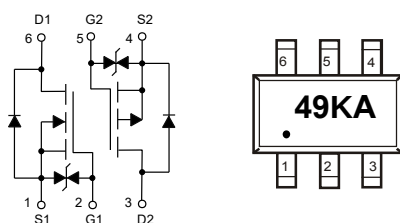
Parameter	Symbol	Rating	Unit
Total Power Dissipation	P _D	150	mW
N-Channel MOSFET			
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current	I _D	0.75	A
Pulsed Drain Current (Note 3)	I _{DM}	3	A
P-Channel MOSFET			
Drain-Source Voltage	V _{DS}	-20	V
Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current	I _D	-0.6	A
Pulsed Drain Current (Note 3)	I _{DM}	-3	A

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

2. Surface Mounted on FR-4 Board Using Minimum Pad Size.

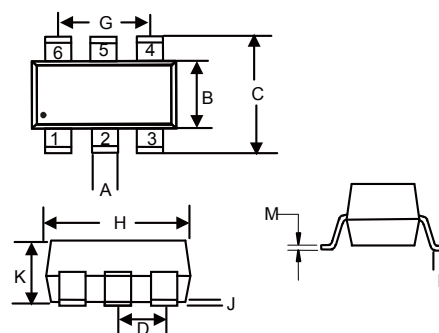
3. Pulse Width Limited by Maximum Junction Temperature.

Internal Structure and Marking Code



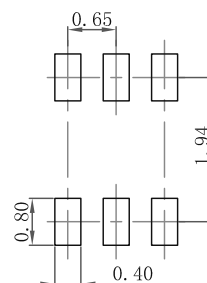
Dual N&P-Channel MOSFET

SOT-363



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.006	0.014	0.15	0.35	
B	0.045	0.053	1.15	1.35	
C	0.079	0.096	2.00	2.45	
D	0.026		0.65		TYP.
G	0.047	0.055	1.20	1.40	
H	0.071	0.087	1.80	2.20	
J	-----	0.004	-----	0.10	
K	0.031	0.043	0.80	1.10	
L	0.010	0.018	0.26	0.46	
M	0.003	0.006	0.08	0.15	

Suggested Solder Pad Layout



N-Channel MOSFET Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	20			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 10V$			± 10	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage ^(Note4)	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.35	0.67	1.1	V
Drain-Source On-Resistance ^(Note4)	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=500mA$		240	300	m Ω
		$V_{GS}=2.5V, I_D=400mA$		320	400	m Ω
		$V_{GS}=1.8V, I_D=200mA$		480	700	m Ω
Forward transconductance	g_{FS}	$V_{DS}=10V, I_D=500mA$	0.8			S
Diode Forward Voltage ^(Note4)	V_{SD}	$V_{GS}=0V, I_S=500mA$			1.2	V
Dynamic Characteristics^(Note5,6)						
Input Capacitance	C_{iss}	$V_{DS}=16V, V_{GS}=0V, f=1MHz$		33		pF
Output Capacitance	C_{oss}			20		
Reverse Transfer Capacitance	C_{rss}			10		
Total Gate Charge	Q_g	$V_{GS}=4.5V, V_{DS}=10V, I_D=1A$		800		pC
Gate-Source Charge	Q_{gs}			290		
Gate-Drain Charge	Q_{gd}			160		
Turn-On Delay Time	$t_{d(on)}$	$V_{GS}=4.5V, V_{DS}=10V, I_{DS}=0.5A, R_G=10\Omega$		4		ns
Turn-On Rise Time	t_r			18		
Turn-Off Delay Time	$t_{d(off)}$			11.6		
Turn-Off Fall Time	t_f			24		

P-Channel MOSFET Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20			V
Gate-Threshold Voltage ^(Note 4)	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.35	-0.64	-1.1	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-20V, V_{GS}=0V$			-1.0	μA
Gate-body Leakage Current	I_{GSS}	$V_{GS}=\pm 10V, V_{DS}=0V$			± 10	μA
Drain-Source On-Resistance ^(Note 4)	$R_{DS(on)}$	$V_{GS}=-4.5V, I_D=-500mA$		0.64	0.85	Ω
		$V_{GS}=-2.5V, I_D=-300mA$		0.92	1.2	
		$V_{GS}=-1.8V, I_D=-200mA$		1.41	2.0	
Forward transconductance	g_{FS}	$V_{DS}=-10V, I_D=-500mA$	0.8			S
Diode Forward Voltage ^(Note 4)	V_{SD}	$V_{GS}=0V, I_S=-500mA$			-1.2	V
Dynamic Characteristics^(Note 5,6)						
Input Capacitance	C_{iss}	$V_{DS}=-16V, V_{GS}=0V, f=1MHz$		40		pF
Output Capacitance	C_{oss}			16		
Reverse Transfer Capacitance	C_{rss}			11		
Total Gate Charge	Q_g	$V_{GS}=-4.5V, V_{DS}=-10V, I_D=-1A$		860		pC
Gate-Source Charge	Q_{gs}			320		
Gate-Drain Charge	Q_{gd}			200		
Turn-on Delay Time	$t_{d(on)}$	$V_{DS}=-10V, V_{GS}=-4.5V, I_D=-500mA, R_G=10\Omega$		3.8		ns
Turn-off Delay Time	$t_{d(off)}$			9.4		
Rise Time	t_r			19		
Fall Time	t_f			23		

Note 4. Pulse Test : Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.

5. Switching characteristics are independent of operating junction temperature.

6. Guaranteed by Design, Not Subject to Production Testing.

Curve Characteristics(N-Channel)

Fig. 1 - Output Characteristics

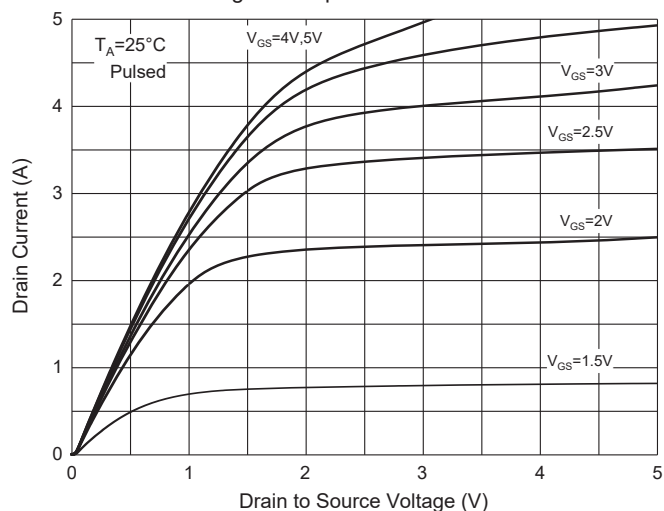


Fig. 2 - Transfer Characteristics

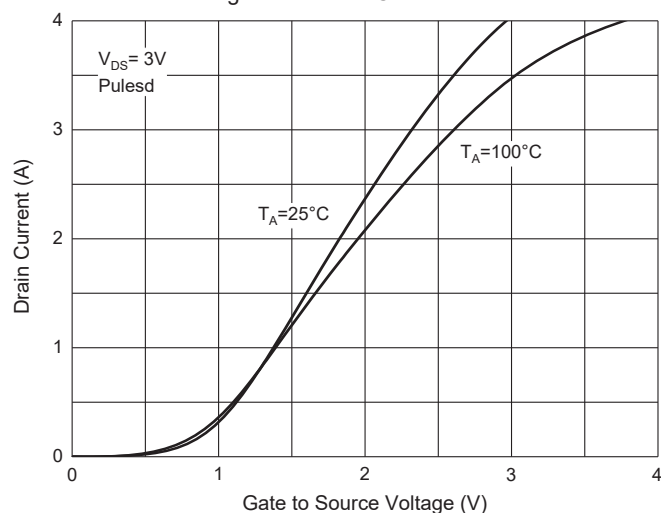


Fig. 3 - $R_{DS(ON)} - I_D$

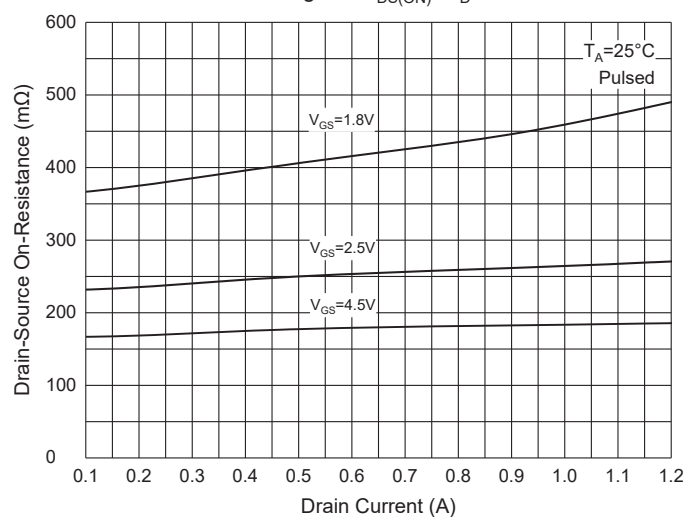


Fig. 4 - $R_{DS(ON)} - V_{GS}$

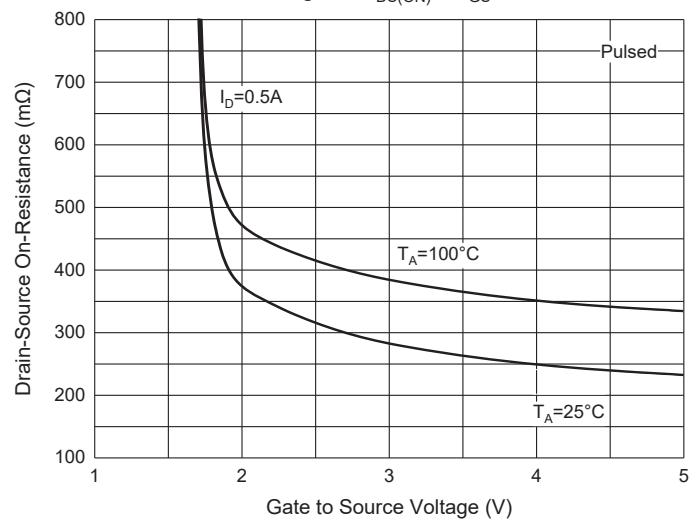


Fig. 5 - $I_S - V_{SD}$

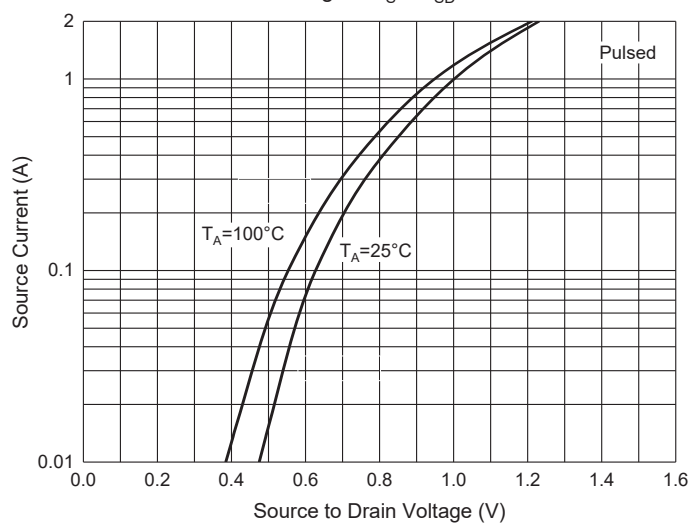
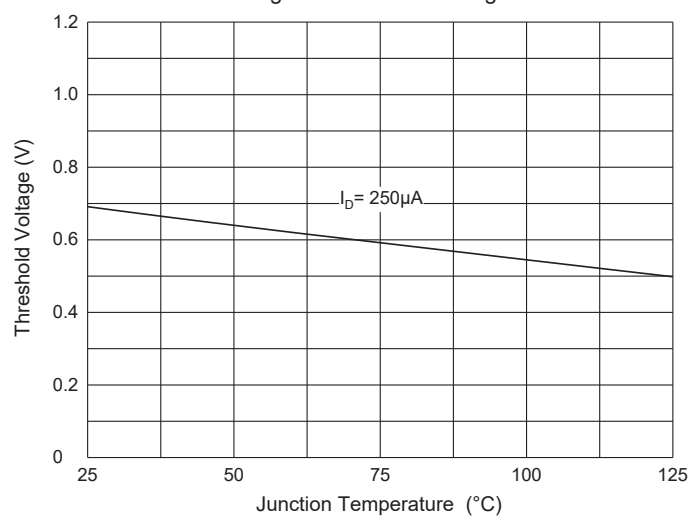


Fig. 6 - Threshold Voltage



Curve Characteristics(N-Channel)

Fig. 7 - Capacitance Characteristics

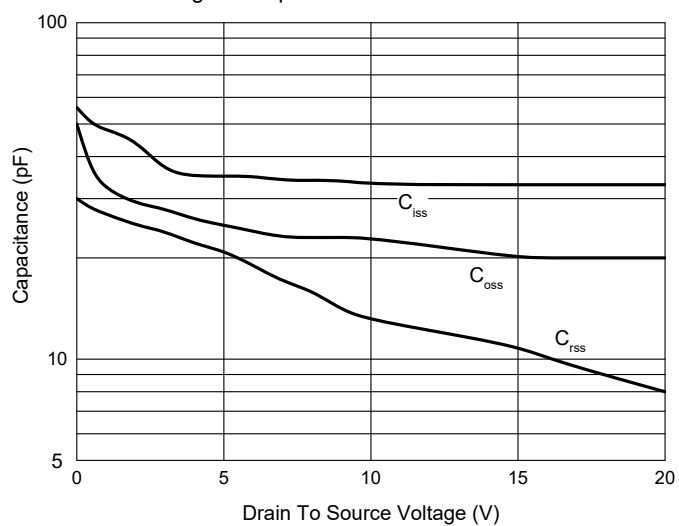
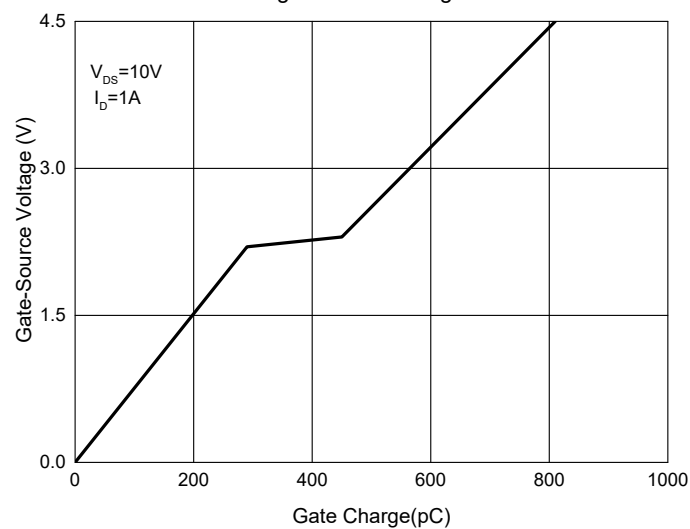


Fig. 8 - Gate Charge



Curve Characteristics(P-Channel)

Fig. 1 - Typical Output Characteristics

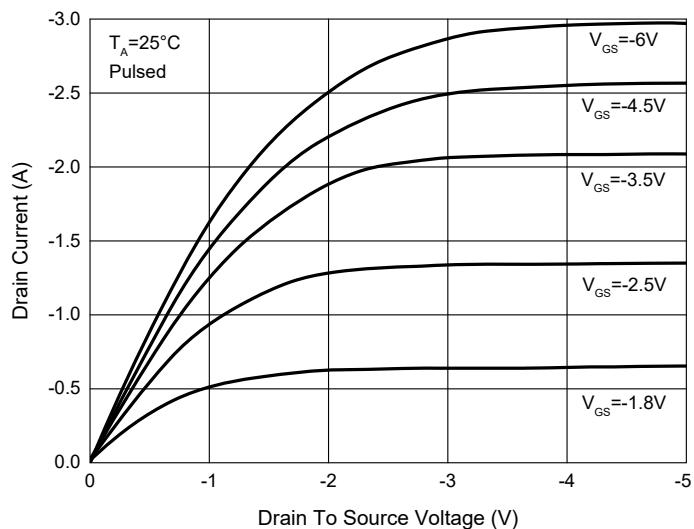


Fig. 2 - Transfer Characteristics

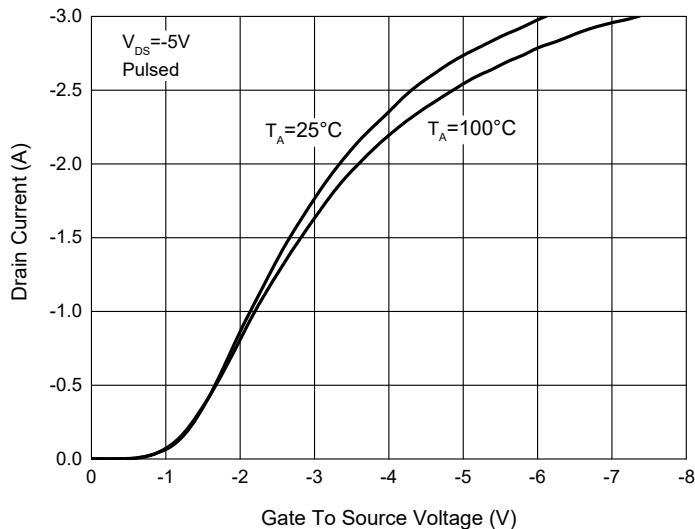


Fig. 3 - $R_{DS(ON)} - I_D$

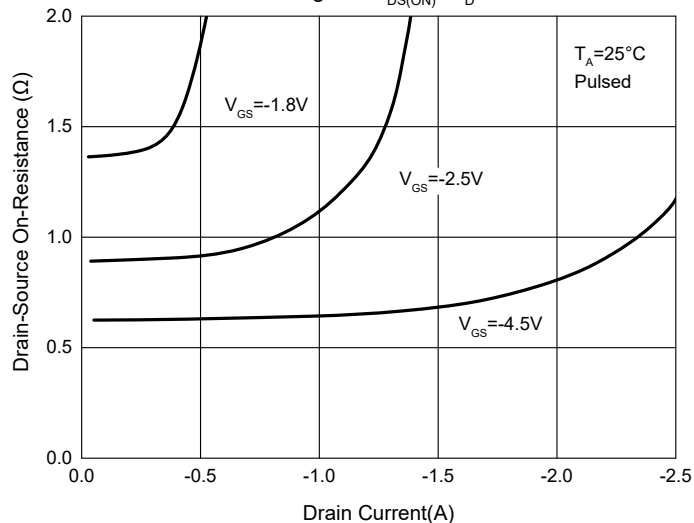


Fig. 4 - $R_{DS(ON)} - V_{GS}$

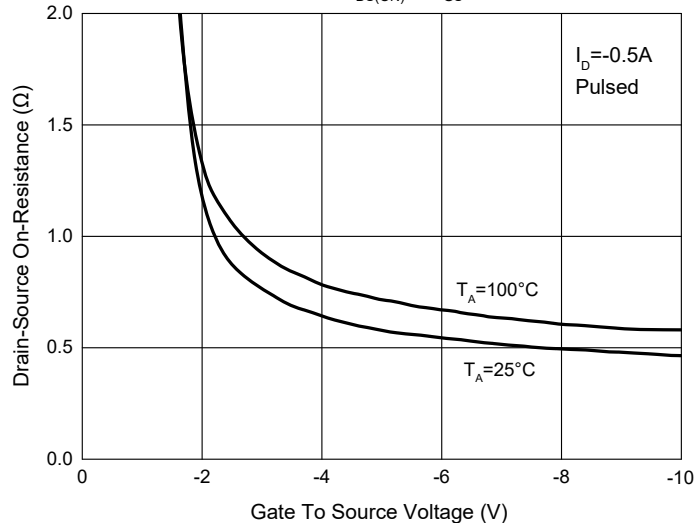


Fig. 5 - $I_S - V_{SD}$

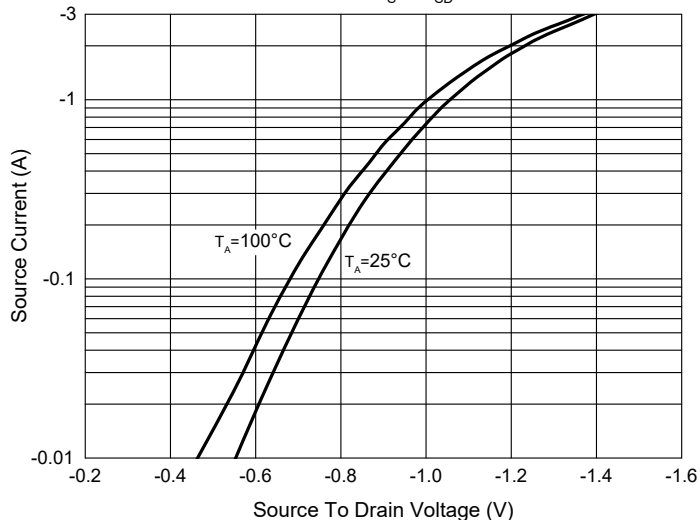
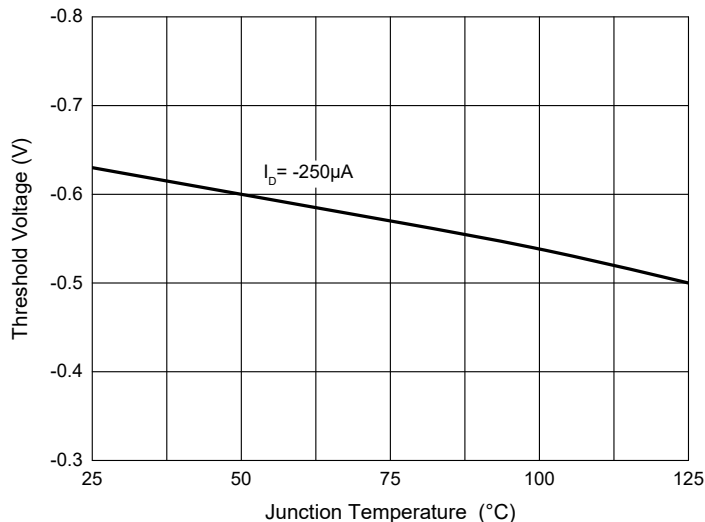


Fig. 6 - Threshold Voltage



Curve Characteristics(P-Channel)

Fig. 7 - Capacitance Characteristics

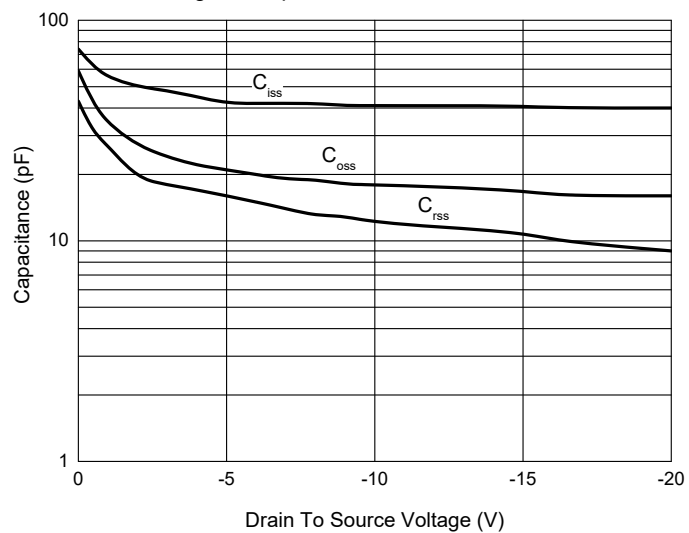
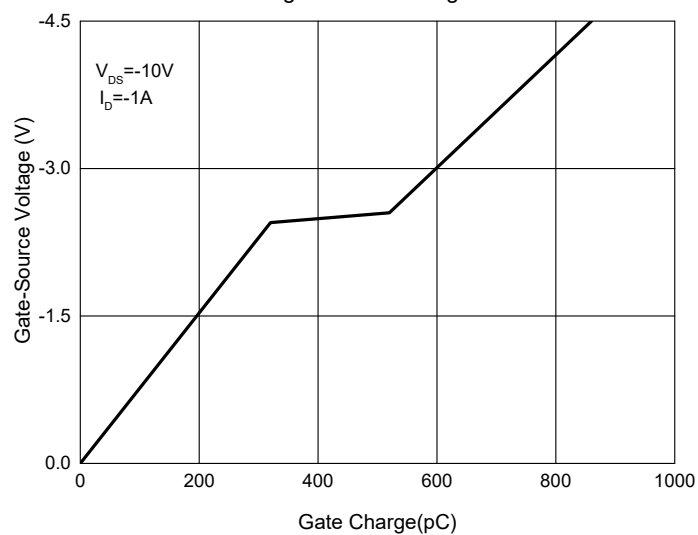


Fig. 8 - Gate Charge



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

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